

DS36954 Quad Differential Bus Transceiver

Check for Samples: [DS36954](#)

FEATURES

- Pinout for SCSI Interface
- Compact 20-Pin PLCC or SOIC Package
- Meets EIA-485 Standard for Multipoint Bus Transmission
- Greater than 60 mA Source/Sink Currents
- Thermal Shutdown Protection
- Glitch-Free Driver Outputs on Power Up and Down

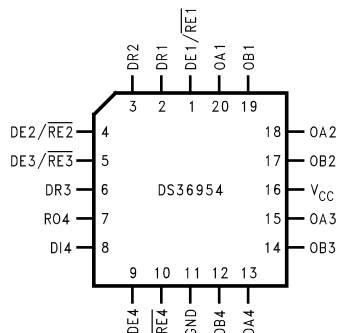
DESCRIPTION

The DS36954 is a low power, quad EIA-485 differential bus transceiver especially suited for high speed, parallel, multipoint, I/O bus applications. A compact 20-pin surface mount PLCC or SOIC package provides high transceiver integration and a very small PC board footprint.

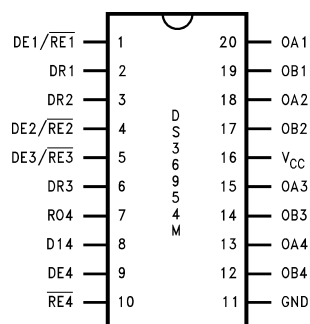
Propagation delay skew between devices is specified to aid in parallel interface designs—limits on maximum and minimum delay times are guaranteed.

Five devices can implement a complete SCSI initiator or target interface. Three transceivers in a package are pinned out for data bus connections. The fourth transceiver, with the flexibility provided by its individual enables, can serve as a control bus transceiver.

Connection Diagram

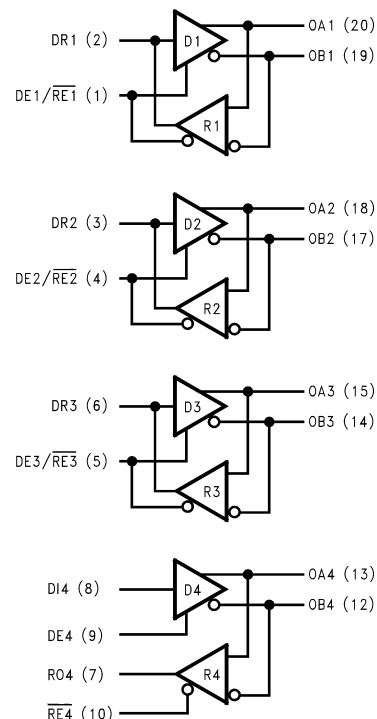


See Package Number FN (S-PQCC-J20)



See Package Number DW (R-PDSO-G20)

Logic Diagram



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2004, Texas Instruments Incorporated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾⁽²⁾

Supply Voltage	7V
Control Input Voltage	$V_{CC} + 0.5V$
Driver Input Voltage	$V_{CC} + 0.5V$
Driver Output Voltage/Receiver Input Voltage	-10V to +15V
Receiver Output Voltage	5.5V
Continuous Power Dissipation @ +25°C	
FN Package	1.73W
DW Package	1.73W
Derate FN Package	13.9 mW/°C above +25°C
Derate DW Package	13.7 mW/°C above +25°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering 4 Sec.)	260°C

- (1) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instrument Sales Office/ Distributors for availability and specifications.

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage, V_{CC}	4.75	5.25	V
Bus Voltage	-7	+12	V
Operating Free Air Temperature (T_A)	0	+70	°C

Electrical Characteristics ⁽¹⁾⁽²⁾

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DRIVER CHARACTERISTICS						
V_{ODL}	Differential Driver Output Voltage (Full Load)	$I_L = 60 \text{ mA}$ $V_{CM} = 0V$	1.5	1.9		V
V_{OD}	Differential Driver Output Voltage (Termination Load)	$R_L = 100\Omega$ (EIA-422) $R_L = 54\Omega$ (EIA-485)	2.0 1.5	2.25 2.0		V
$\Delta IVODI$	Change in Magnitude of Driver Differential Output Voltage for Complementary Output States	$R_L = 54$ or 100Ω ⁽³⁾ (Figure 1) (EIA-422/485)			0.2	V
V_{OC}	Driver Common Mode Output Voltage ⁽⁴⁾	$R_L = 54\Omega$ (Figure 1) (EIA-485)			3.0	V
$\Delta IVOCI$	Change in Magnitude of Common Mode Output Voltage	⁽³⁾ (Figure 1) (EIA-422/485)			0.2	V
V_{OH}	Output Voltage High	$I_{OH} = -55 \text{ mA}$	2.7	3.2		V
V_{OL}	Output Voltage Low	$I_{OL} = 55 \text{ mA}$		1.4	1.7	V
V_{IH}	Input Voltage High		2.0			V
V_{IL}	Input Voltage Low				0.8	V

- (1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.
- (2) All typicals are given for $V_{CC} = 5V$ and $T_A = 25^\circ\text{C}$.
- (3) $\Delta IVODI$ and $\Delta IVOCI$ are changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input changes state.
- (4) In EIA Standards EIA-422 and EIA-485, V_{OC} , which is the average of the two output voltages with respect to ground, is called output offset voltage, V_{OS} .

Electrical Characteristics ⁽¹⁾⁽²⁾ (continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions		Min	Typ	Max	Units
V _{CL}	Input Clamp Voltage	I _{CL} = -18 mA				-1.5	V
I _{IH}	Input High Current	V _{IN} = 2.4V ⁽⁵⁾				20	μA
I _{IL}	Input Low Current	V _{IN} = 0.4V ⁽⁵⁾				-20	μA
I _{OSC}	Driver Short-Circuit Output Current ⁽⁶⁾	V _O = -7V (EIA-485)		-130	-250	mA	
		V _O = 0V (EIA-422)		-90	-150	mA	
		V _O = +12V (EIA-485)		130	250	mA	
RECEIVER CHARACTERISTICS							
I _{OSR}	Short Circuit Output Current	V _O = 0V ⁽⁶⁾		-15	-28	-75	mA
I _{OZ}	TRI-STATE Output Current	V _O = 0.4V to 2.4V				20	μA
V _{OH}	Output Voltage High	V _{ID} = 0.2V, I _{OH} = 0.4 mA		2.4	3.0		V
V _{OL}	Output Voltage Low	V _{ID} = -0.2V, I _{OL} = 4 mA			0.35	0.5	V
V _{TH}	Differential Input High Threshold Voltage	V _O = V _{OH} , I _O = -0.4 mA (EIA-422/485)			0.03	0.2	V
V _{TL}	Differential Input Low Threshold Voltage ⁽⁷⁾	V _O = V _{OL} , I _O = 4.0 mA (EIA-422/485)		-0.2 0	-0.03		V
V _{HST}	Hysteresis ⁽⁸⁾	V _{CM} = 0V		35	60		mV
DRIVER AND RECEIVER CHARACTERISTICS							
V _{IH}	Enable Input Voltage High			2.0			V
V _{IL}	Enable Input Voltage Low					0.8	V
V _{CL}	Enable Input Clamp Voltage	I _{CL} = -18 mA				-1.5	V
I _{IN}	Line Input Current ⁽⁹⁾	Other Input = 0V DE/ $\overline{\text{RE}}$ = 0.8V DE4 = 0.8V	V _I = +12V		0.5	1.0	mA
			V _I = -7V		-0.45	-0.8	mA
I _{ING}	Line Input Current ⁽⁹⁾	Other Input = 0V DE/ $\overline{\text{RE}}$ and DE4 = 2V V _{CC} = 3.0V T _A = +25°C	V _I = +12V			1.0	mA
			V _I = -7V			-0.8	mA
I _{IH}	Enable Input Current High	V _{IN} = 2.4V DE/ $\overline{\text{RE}}$	V _{CC} = 3.0V		1	40	μA
			V _{CC} = 4.75V		1		μA
			V _{CC} = 5.25V		1	40	μA
		V _{IN} = 2.4V DE4 or $\overline{\text{RE4}}$	V _{CC} = 3.0V		1	20	μA
			V _{CC} = 5.25V		1	20	μA
I _{IL}	Enable Input Current Low	V _{IN} = 0.8V DE/ $\overline{\text{RE}}$	V _{CC} = 3.0V		-6	-40	μA
			V _{CC} = 4.75V		-12		μA
			V _{CC} = 5.25V		-14	-40	μA
		V _{IN} = 0.8V DE4 or $\overline{\text{RE4}}$	V _{CC} = 3.0V		-3	-20	μA
			V _{CC} = 5.25V		-7	-20	μA
I _{CCD}	Supply Current ⁽¹⁰⁾	No Load, DE/ $\overline{\text{RE}}$ and DE4 = 2.0V			75	90	mA
I _{CCR}	Supply Current ⁽¹⁰⁾	No Load, DE/ $\overline{\text{RE}}$ and $\overline{\text{RE4}}$ = 0.8V			50	70	mA

(5) I_{IH} and I_{IL} include driver input current and receiver TRI-STATE leakage current on DR(1–3).

(6) Short one output at a time.

(7) Threshold parameter limits specified as an algebraic value rather than by magnitude.

(8) Hysteresis defined as V_{HST} = V_{TH} - V_{TL}.

(9) I_{IN} includes the receiver input current and driver TRI-STATE leakage current.

(10) Total package supply current.

Switching Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DRIVER SINGLE-ENDED CHARACTERISTICS						
t _{PZH}	Output Enable Time to High Level	R _L = 110Ω (Figure 6) (Figure 8) (Figure 6) (Figure 8)		35	40	ns
t _{PZL}	Output Enable Time to Low Level			25	40	ns
t _{PHZ}	Output Disable Time to High Level			15	25	ns
t _{PLZ}	Output Disable Time to Low Level			35	40	ns
DRIVER DIFFERENTIAL CHARACTERISTICS						
t _r , t _f	Rise and Fall Time	R _L = 54Ω C _L = 50 pF C _D = 15 pF (Figure 3 Figure 4 ⁽¹⁾)		13	16	ns
t _{PLHD}	Differential Propagation		9	15	19	ns
t _{PHLD}	Delays ⁽²⁾		9	12	19	ns
t _{SKD}	t _{PLHD} – t _{PHLD} Diff. Skew			3	6	ns
RECEIVER CHARACTERISTICS						
t _{PLHD}	Differential Propagation Delays	C _L = 15 pF V _{CM} = 2.0V (Figure 10)	9	14	19	ns
t _{PHLD}			9	13	19	ns
t _{SKD}	t _{PLHD} – t _{PHLD} Diff. Receiver Skew		1	3	ns	
t _{PZH}	Output Enable Time to High Level	C _L = 15 pF (Figure 15)		15	22	ns
t _{PZL}	Output Enable Time to Low Level			20	30	ns
t _{PHZ}	Output Disable Time from High Level			20	30	ns
t _{PLZ}	Output Disable Time from Low Level			17	25	ns

(1) Propagation Delay Timing for Calculations of Driver Differential Propagation Delays

(2) Differential propagation delays are calculated from single-ended propagation delays measured from driver input to the 20% and 80% levels on the driver outputs ([Figure 16](#)) .

PARAMETER MEASUREMENT INFORMATION

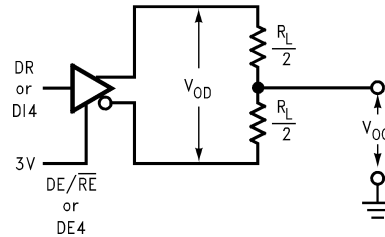


Figure 1. Driver V_{OD} and V_{OC} ⁽³⁾

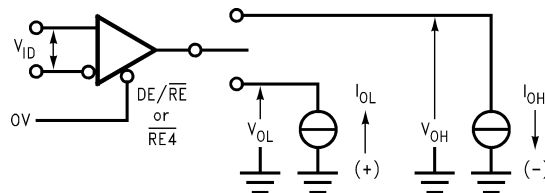
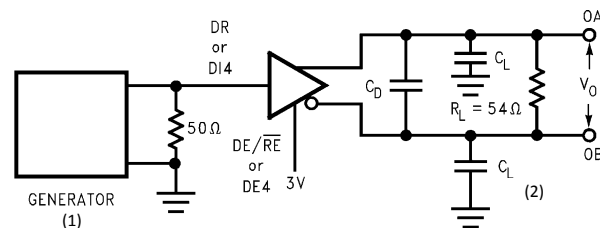
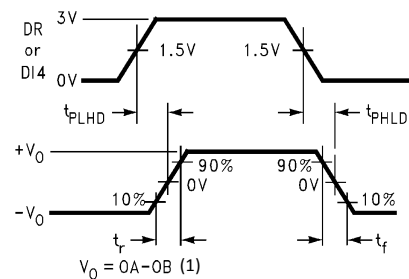


Figure 2. Receiver V_{OH} and V_{OL}



- (1) The input pulse is supplied by a generator having the following characteristics: $f = 1.0$ MHz, 50% duty cycle, $\text{trand} \text{ tf} < 6.0$ ns, $Z_O = 50 \Omega$
- (2) C_L includes probe and stray capacitance.

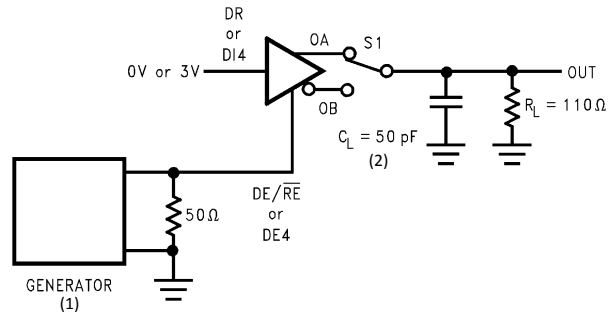
Figure 3. Driver Differential Propagation Delay Load Circuit



- (1) Differential propagation delays are calculated from single-ended propagation delays measured from driver input to the 20% and 80% levels on the driver outputs (Figure 16).

Figure 4. Driver Differential Propagation Delays and Transition Times

(3) C_L includes probe and stray capacitance.



S1 to OA for DI = 3V

S1 to OB for DI = 0V

- (1) The input pulse is supplied by a generator having the following characteristics: $f = 1.0$ MHz, 50% duty cycle, $t_{\text{rand}} t_f < 6.0$ ns, $Z_O = 50\Omega$.
- (2) C_L includes probe and stray capacitance.

Figure 5.

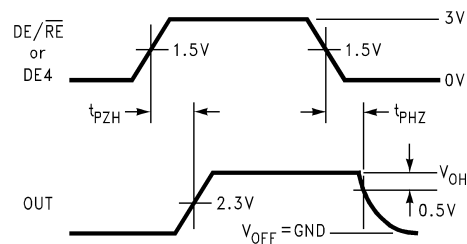
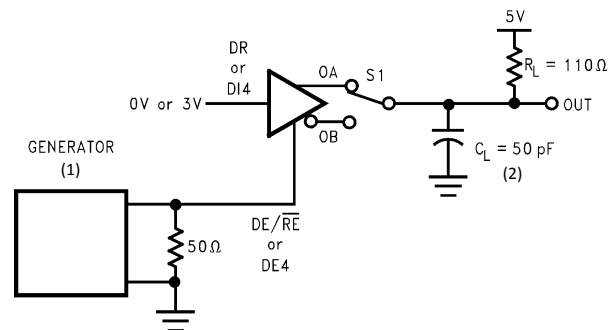


Figure 6. Driver Enable and Disable Timing (t_{PZH} , t_{PHZ})



S1 to OA for DI = 0V

S1 to OB for DI = 3V

- (1) The input pulse is supplied by a generator having the following characteristics: $f = 1.0$ MHz, 50% duty cycle, $t_{\text{rand}} t_f < 6.0$ ns, $Z_O = 50\Omega$.
- (2) C_L includes probe and stray capacitance.

Figure 7.

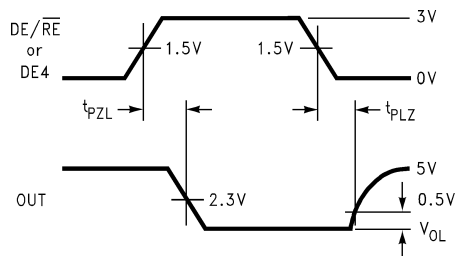
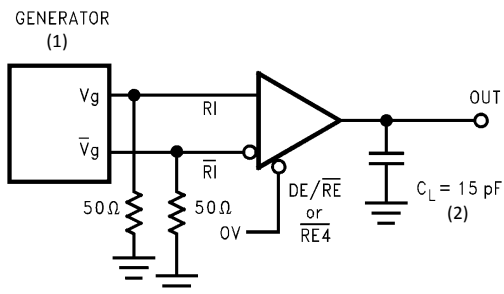


Figure 8. Driver Enable and Disable Timing (t_{PZL} , t_{PLZ})



- (1) The input pulse is supplied by a generator having the following characteristics: $f = 1.0$ MHz, 50% duty cycle, $\text{trand} \text{ tf} < 6.0$ ns, $Z_O = 50\Omega$.
- (2) C_L includes probe and stray capacitance.

Figure 9.

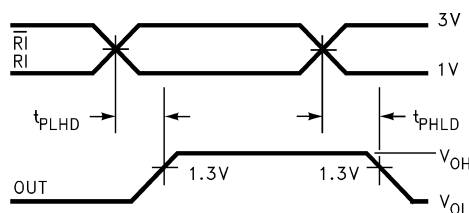
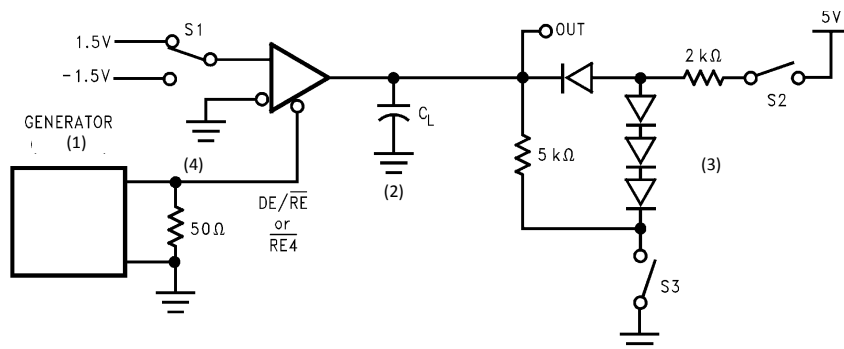
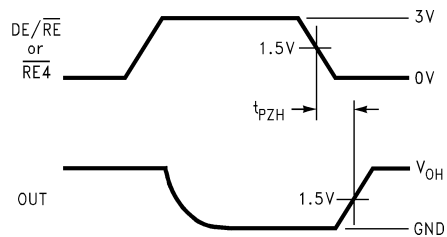


Figure 10. Receiver Differential Propagation Delay Timing

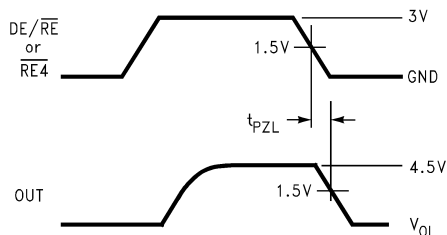


- (1) The input pulse is supplied by a generator having the following characteristics: $f = 1.0$ MHz, 50% duty cycle, $\text{trand} \text{ tf} < 6.0$ ns, $Z_O = 50\Omega$.
- (2) C_L includes probe and stray capacitance.
- (3) Diodes are 1N916 or equivalent.
- (4) On transceivers 1–3 the driver is loaded with receiver input conditions when DE/RE is high. Do not exceed the package power dissipation limit when testing.

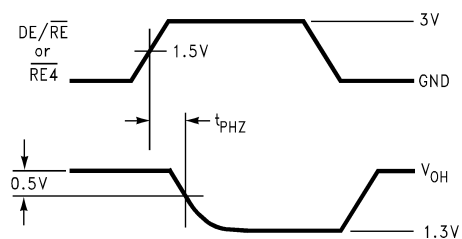
Figure 11.



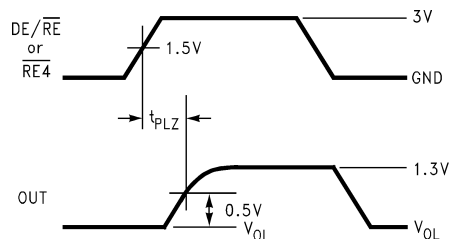
S1 1.5V
S2 Open
S3 Closed

Figure 12.

S1 -1.5V
S2 Closed
C3 Open

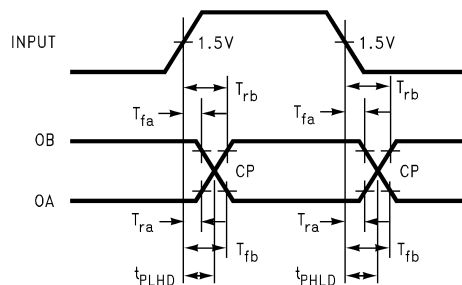
Figure 13.

S1 1.5V
S2 Closed
C3 Closed

Figure 14.

S1 -1.5V
S2 Closed
C3 Closed

Figure 15. Receiver Enable and Disable Timing



$$T_{CP} = \frac{(T_{fb} \times T_{rb}) - (T_{ra} \times T_{fa})}{T_{rb} - T_{ra} - T_{fa} + T_{fb}}$$

T_{ra} , T_{rb} , T_{fa} and T_{fb} are propagation delay measurements to the 20% and 80% levels.

T_{CP} = Crossing Point

Figure 16. Propagation Delay Timing for Calculations of Driver Differential Propagation Delays

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
DS36954M	ACTIVE	SOIC	DW	20	36	TBD	Call TI	Call TI	0 to 70	DS36954 M	Samples
DS36954M/NOPB	ACTIVE	SOIC	DW	20	36	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 70	DS36954 M	Samples
DS36954MX	ACTIVE	SOIC	DW	20	1000	TBD	Call TI	Call TI	0 to 70	DS36954 M	Samples
DS36954MX/NOPB	ACTIVE	SOIC	DW	20	1000	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 70	DS36954 M	Samples
DS36954VX	ACTIVE	PLCC	FN	20	1000	TBD	Call TI	Call TI	0 to 70	DS36954V	Samples
DS36954VX/NOPB	ACTIVE	PLCC	FN	20	1000	Green (RoHS & no Sb/Br)	CU SN	Level-2A-250C-4 WEEK	0 to 70	DS36954V	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS36954MX	SOIC	DW	20	1000	330.0	24.4	10.9	13.3	3.25	12.0	24.0	Q1
DS36954MX/NOPB	SOIC	DW	20	1000	330.0	24.4	10.9	13.3	3.25	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS36954MX	SOIC	DW	20	1000	367.0	367.0	45.0
DS36954MX/NOPB	SOIC	DW	20	1000	367.0	367.0	45.0

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE

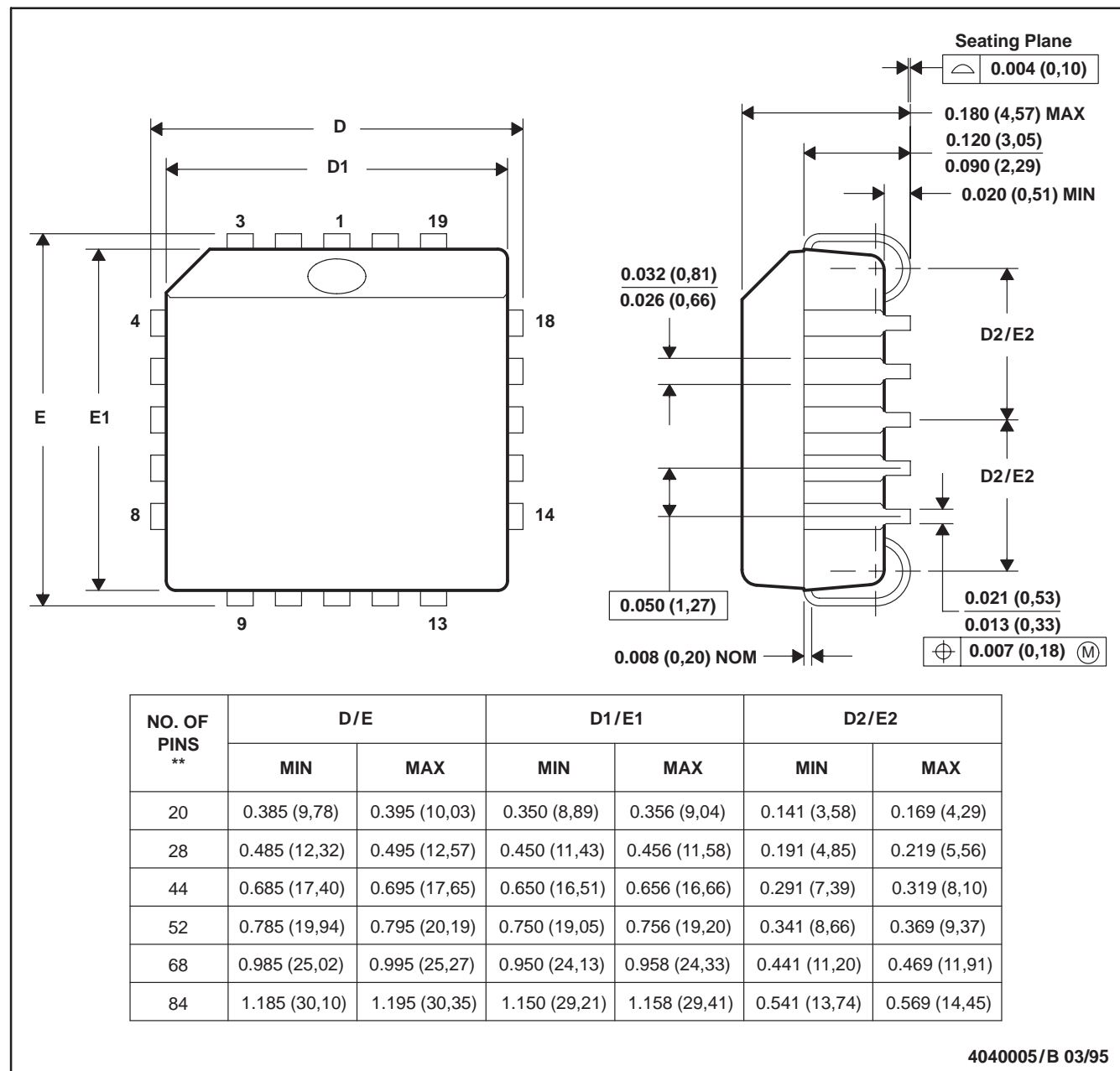


- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AC.

FN (S-PQCC-J**)

PLASTIC J-LEADED CHIP CARRIER

20 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-018

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com